

MD1S~MD10S

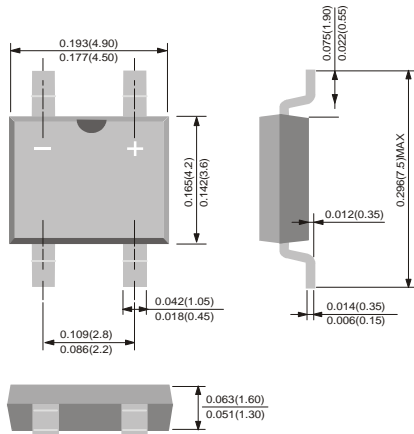
BRIDGE RECTIFIER

VOLTAGE 100 to 1000Volts CURRENT 0.8 Amperes



MBF

Unit : inch(mm)



FEATURES

- Plastic material used carries Underwriters Laboratory recognition 94V-0
- Low leakage
- Surge overload rating-- 30 amperes peak
- Ideal for printed circuit board
- Exceeds environmental standards of MIL-S-19500
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: Reliable low cost construction utilizing molded plastic technique results in
- inexpensive product
- Terminals: Lead solderable per MIL-STD-750, Method 2026
- Polarity: Polarity symbols molded or marking on body
- Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, Resistive or inductive load. For capacitive load, derate current by 20%

| PARAMETER | SYMBOL | MD1S | MD2S | MD4S | MD5S | MD8S | MD10S | UNITS |
|--|------------------------------------|-------------|------|------|------|------|-------|------------------|
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Bridge Input Voltage | V_{RMS} | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | V_R | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward Current $T_A=55^{\circ}C$ $T_A=25^{\circ}C$ | $I_{F(AV)}$ | 0.8 | | | | | | A |
| Peak Forward Surge Current : 8.3ms single half sine-wave superimposed on rated load (JEDEC method) | I_{FSM} | 30 | | | | | | A |
| Power Dissipation at $T_A=25^{\circ}C$ | P_D | 1.4 | | | | | | W |
| I ² t Rating for fusing (t<8.35ms) | I ² t | 3.735 | | | | | | A ² S |
| Maximum Forward Voltage Drop per Bridge Element at 0.5A | V_F | 1.0 | | | | | | V |
| Maximum DC Reverse Current at Rated DC Blocking Voltage $T_J=25^{\circ}C$ $T_J=125^{\circ}C$ | I_R | 10.0 500 | | | | | | μA |
| Typical Junction capacitance (Note 1) | C_J | 25 | | | | | | pF |
| Typical thermal resistance (Note 2) | $R_{\theta JA}$ $R_{\theta JL}$ | 85 20 | | | | | | $^{\circ}C / W$ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | | | | | | $^{\circ}C$ |

NOTES:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts.
2. Thermal resistance from junction to ambient mounted on 5cmX6cm P.C.B. with minimum copper pads.

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RATING AND CHARACTERISTIC CURVES

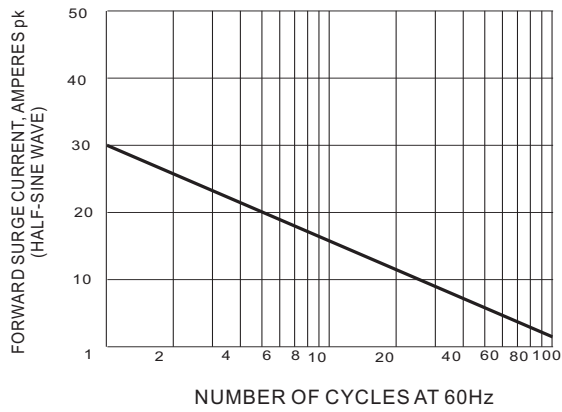


Fig.1 MAXIMUM NON-REPETITIVE SURGE CURRENT

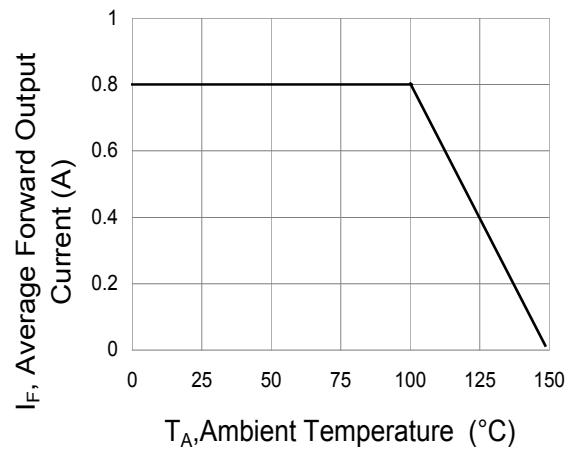


Fig.2 Derating Curve For Output Rectified Current

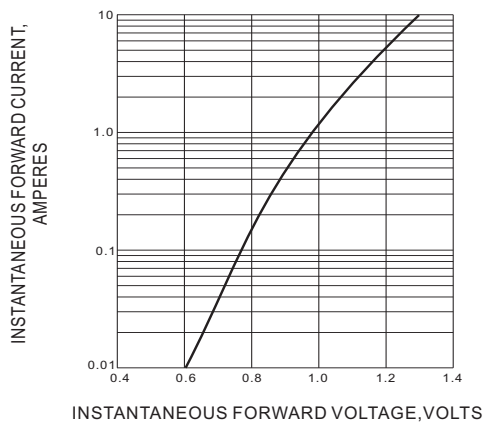


Fig.3 TYPICAL FORWARD CHARACTERISTICS

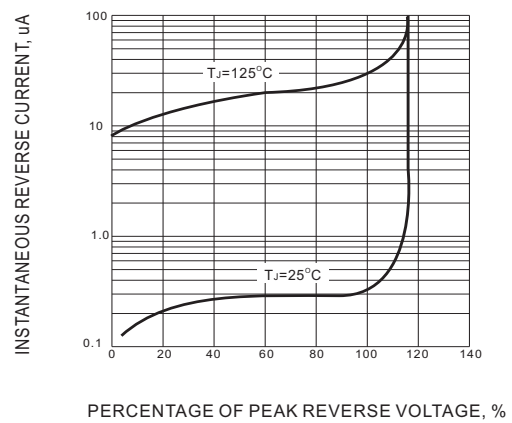


Fig.4 TYPICAL REVERSE CHARACTERISTICS